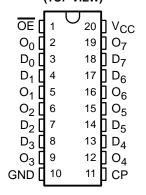
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- Function and Pinout Compatible With FCT and F Logic
- 25-Ω Output Series Resistors to Reduce Transmission-Line Reflection Noise
- Reduced V<sub>OH</sub> (Typically = 3.3 V) Version of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- 3-State Outputs
- 12-mA Output Sink Current
   15-mA Output Source Current
- Edge-Triggered D-Type Inputs
- 250-MHz Typical Switching Rate

## SN74FCT2374T . . . Q OR SO PACKAGE (TOP VIEW)



### description

The CY74FCT2374T is a high-speed, low-power, octal D-type flip-flop featuring separate D-type inputs for each flip-flop. On-chip termination resistors at the outputs reduce system noise caused by reflections. The CY74FCT2374T can replace the CY74FCT374T to reduce noise in an existing design. The device has 3-state outputs for bus-oriented applications. A buffered clock (CP) and output-enable ( $\overline{OE}$ ) inputs are common to all flip-flops. The flip-flops in the CY74FCT2374T store the state of their individual data (D) inputs that meet the setup-time and hold-time requirements on the low-to-high CP transition. When  $\overline{OE}$  is low, the contents of the flip-flops are available at the outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state. The state of  $\overline{OE}$  does not affect the state of the flip-flops.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



#### **ORDERING INFORMATION**

TA	PAC	(AGE <sup>†</sup>	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP - Q	Tape and reel	5.2	CY74FCT2374CTQCT	FCT2374C
	SOIC - SO	Tube	5.2	CY74FCT2374CTSOC	FCT2374C
	3010 - 30	Tape and reel	5.2	CY74FCT2374CTSOCT	FC12374C
-40°C to 85°C	QSOP - Q	Tape and reel	6.5	CY74FCT2374ATQCT	FCT2374A
-40 C to 65 C	SOIC - SO	Tube	6.5	CY74FCT2374ATSOC	FCT2374A
	3010 - 30	Tape and reel	6.5	CY74FCT2374ATSOCT	FC12374A
	SOIC - SO	Tube	10	CY74FCT2374TSOC	FCT2374
	3010 - 30	Tape and reel	10	CY74FCT2374TSOCT	FC12374

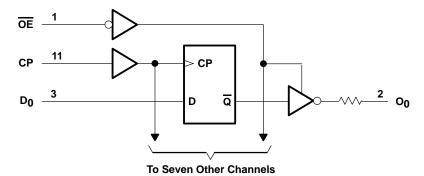
<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLE**

	INPUTS	OUTPUT	
D	СР	OE	0
Н	<b>↑</b>	L	Н
L	$\uparrow$	L	L
Х	Χ	Н	Z

 $H = High logic level, L = Low logic level, X = Don't care, Z = High-impedance state, <math>\uparrow$  = Low-to-high clock transition

## logic diagram (positive logic)





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## absolute maximum rating over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential	$-0.5$ V to 7 V
DC input voltage range	$-0.5\;V$ to 7 $V$
DC output voltage range	$\dots$ –0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 1): Q package	68°C/W
SO package	58°C/W
Ambient temperature range with power applied, T <sub>A</sub>	–65°C to 135°C
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.75	5	5.25	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
ІОН	High-level output current			-15	mA
loL	Low-level output current			12	mA
TA	Operating free-air temperature	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation.



NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
VIK	V <sub>CC</sub> = 4.75 V,	$I_{IN} = -18 \text{ mA}$			-0.7	-1.2	V
VOH	$V_{CC} = 4.75 V$ ,	$I_{OH} = -15 \text{ mA}$		2.4	3.3		V
V <sub>OL</sub>	$V_{CC} = 4.75 V$ ,	$I_{OL} = 12 \text{ mA}$			0.3	0.55	V
ROUT	$V_{CC} = 4.75 V$ ,	$I_{OL} = 12 \text{ mA}$		20	25	40	Ω
V <sub>hys</sub>	All inputs				0.2		V
lį	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = V_{CC}$				5	μΑ
lн	$V_{CC} = 5.25 \text{ V},$	V <sub>IN</sub> = 2.7 V				±1	μΑ
I <sub>ΙL</sub>	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 0.5 V$				±1	μΑ
lozh	$V_{CC} = 5.25 \text{ V},$	V <sub>OUT</sub> = 2.7 V				10	μΑ
lozL	$V_{CC} = 5.25 \text{ V},$	V <sub>OUT</sub> = 0.5 V				-10	μΑ
los <sup>‡</sup>	V <sub>CC</sub> = 5.25 V,	VOUT = 0 V		-60	-120	-225	mA
l <sub>off</sub>	$V_{CC} = 0 V$ ,	V <sub>OUT</sub> = 4.5 V				±1	μΑ
Icc	$V_{CC} = 5.25 \text{ V},$	$V_{IN} \le 0.2 V$ ,	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2	mA
Δl <sub>CC</sub>	$V_{CC} = 5.25 \text{ V}, V_{IN} = 3.25 \text{ V}$	3.4 V\$, f <sub>1</sub> = 0, Outputs ope	en		0.5	2	mA
I <sub>CCD</sub> ¶	$\frac{V_{CC}}{OE}$ = 5.25 V, Output $OE$ = GND, $V_{IN} \le 0.2$	ts open, One input switching $V$ or $V_{IN} \ge V_{CC} - 0.2 \text{ V}$	ng at 50% duty cycle,		0.06	0.12	mA/ MHz
	V <sub>CC</sub> = 5.25 V,	One bit switching at f <sub>1</sub> = 5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{V}$		0.7	1.4	
I <sub>C</sub> #	Outputs open,	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1.2	3.4	m ^
I.C.,	$\frac{f_0}{OE} = 10 \text{ MHz},$ OE = GND	Eight bits switching at f <sub>1</sub> = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1.6	3.2	mA
		at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		3.9	12.2	
C <sub>i</sub>					5	10	pF
Co					9	12	pF

<sup>†</sup> Typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

 $^{\#}$ IC = ICC +  $\Delta$ ICC  $\times$  DH  $\times$  NT + ICCD ( $f_0/2 + f_1 \times N_1$ )

Where:

I<sub>C</sub> = Total supply current

ICC = Power-supply current with CMOS input levels

 $\Delta I_{CC}$  = Power-supply current for a TTL high input ( $V_{IN}$  = 3.4 V)

 $D_H$  = Duty cycle for TTL inputs high  $N_T$  = Number of TTL inputs at  $D_H$ 

ICCD = Dynamic current caused by an input transition pair (HLH or LHL)

f<sub>0</sub> = Clock frequency for registered devices, otherwise zero

f<sub>1</sub> = Input signal frequency

N<sub>1</sub> = Number of inputs changing at f<sub>1</sub>

All currents are in milliamperes and all frequencies are in megahertz.

Values for these conditions are examples of the I<sub>CC</sub> formula.



Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, Ios tests should be performed last.

<sup>§</sup> Per TTL-driven input (V<sub>IN</sub> = 3.4 V); all other inputs at V<sub>CC</sub> or GND

<sup>¶</sup> This parameter is derived for use in total power-supply calculations.

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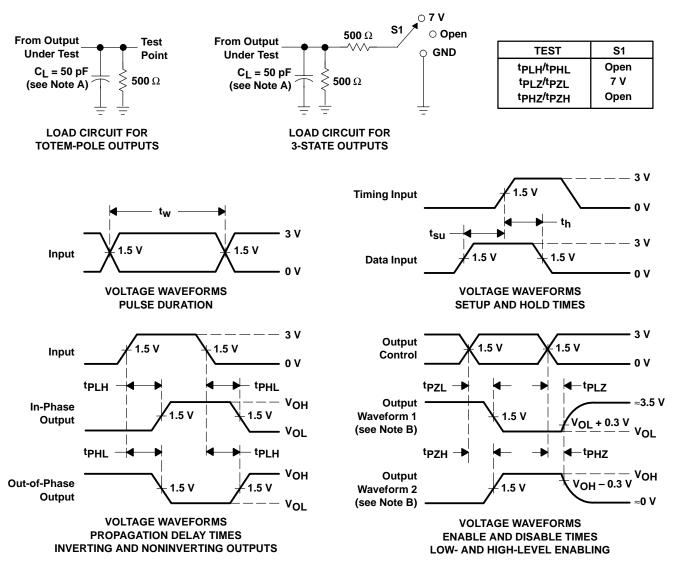
# timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		CY74FCT2374T CY74FCT2374AT		CY74FCT2	2374CT	UNIT		
		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t <sub>W</sub>	Pulse duration, CP	7		5		4		ns
t <sub>su</sub>	Setup time, data before CP↑	2		2		1.5		ns
th	Hold time, data after CP↑	1.5		1.5		1		ns

## switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	CY74FC	CY74FCT2374T		2374AT	CY74FCT	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNII
t <sub>PLH</sub>	СР	0	2	10	2	6.5	2	5.2	ns
t <sub>PHL</sub>			2	10	2	6.5	2	5.2	115
<sup>t</sup> PZH	ŌĒ	0	1.5	12.5	1.5	6.5	1.5	6.2	
tpZL	OE		1.5	12.5	1.5	6.5	1.5	6.2	ns
t <sub>PHZ</sub>	ŌĒ	0	1.5	8	1.5	5.5	1.5	5	
<sup>t</sup> PLZ	OE		1.5	8	1.5	5.5	1.5	5	ns

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





## PACKAGE OPTION ADDENDUM



10-Dec-2020

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CY74FCT2574ATQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2574A	Samples
CY74FCT2574ATSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2574A	Samples
CY74FCT2574CTQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2574C	Samples
CY74FCT2574CTSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2574C	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## **PACKAGE OPTION ADDENDUM**

10-Dec-2020

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## **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT2574ATQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2574CTQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

## **PACKAGE MATERIALS INFORMATION**

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## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT2574ATQCT	SSOP	DBQ	20	2500	356.0	356.0	35.0
CY74FCT2574CTQCT	SSOP	DBQ	20	2500	356.0	356.0	35.0

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022

## **TUBE**



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CY74FCT2574ATSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT2574CTSOC	DW	SOIC	20	25	507	12.83	5080	6.6

DBQ (R-PDSO-G20)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AD.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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